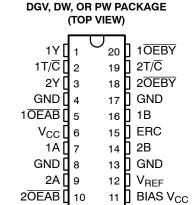
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#### **FEATURES**

- TI-OPC™ Circuitry Limits Ringing on Unevenly Loaded Backplanes
- OEC<sup>™</sup> Circuitry Improves Signal Integrity and Reduces Electromagnetic Interference
- Bidirectional Interface Between GTLP Signal Levels and LVTTL Logic Levels
- Split LVTTL Port Provides a Feedback Path for Control and Diagnostics Monitoring
- LVTTL Interfaces Are 5-V Tolerant
- High-Drive GTLP Outputs (100 mA)
- LVTTL Outputs (–24 mA/24 mA)
- Variable Edge-Rate Control (ERC) Input Selects GTLP Rise and Fall Times for Optimal Data-Transfer Rate and Signal Integrity in Distributed Loads
- I<sub>off</sub>, Power-Up 3-State, and BIAS V<sub>CC</sub> Support Live Insertion
- Polarity Control Selects True or Complementary Outputs
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



#### DESCRIPTION/ORDERING INFORMATION

The SN74GTLP1395 is two 1-bit, high-drive, 3-wire bus transceivers that provide LVTTL-to-GTLP and GTLP-to-LVTTL signal-level translation for applications, such as primary and secondary clocks, that require individual output-enable and true/complement controls. The device allows for transparent and inverted transparent modes of data transfer with separate LVTTL input and LVTTL output pins, which provide a feedback path for control and diagnostics monitoring. The device provides a high-speed interface between cards operating at LVTTL logic levels and a backplane operating at GTLP signal levels and is designed especially to work with the Texas Instruments 3.3-V 1394 backplane physical-layer controller. High-speed (about three times faster than standard LVTTL or TTL) backplane operation is a direct result of GTLP reduced output swing (<1 V), reduced input threshold levels, improved differential input, OEC<sup>TM</sup> circuitry, and TI-OPC<sup>TM</sup> circuitry. Improved GTLP OEC and TI-OPC circuitry minimizes bus settling time, and have been designed and tested using several backplane models. The high drive allows incident-wave switching in heavily loaded backplanes, with equivalent load impedance down to 11 Ω.

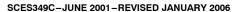
GTLP is the Texas Instruments derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD 8-3. The ac specification of the SN74GTLP1395 is given only at the preferred higher noise margin GTLP, but the user has the flexibility of using this device at either GTL ( $V_{TT} = 1.2 \text{ V}$  and  $V_{REF} = 0.8 \text{ V}$ ) or GTLP ( $V_{TT} = 1.5 \text{ V}$  and  $V_{REF} = 1 \text{ V}$ ) signal levels. For information on using GTLP devices in FB+/BTL applications, refer to TI application reports, *Texas Instruments GTLP Frequently Asked Questions*, literature number SCEA019, and *GTLP in BTL Applications*, literature number SCEA017.

Normally, the B port operates at GTLP signal levels. The A-port and control inputs operate at LVTTL logic levels, but are 5-V tolerant and are compatible with TTL or 5-V CMOS devices.  $V_{REF}$  is the B-port differential input reference voltage.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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#### **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

This device is fully specified for live-insertion applications using  $I_{\text{off}}$ , power-up 3-state, and BIAS  $V_{\text{CC}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict. The BIAS  $V_{\text{CC}}$  circuitry precharges and preconditions the B-port input/output connections, preventing disturbance of active data on the backplane during card insertion or removal, and permits true live-insertion capability.

This GTLP device features TI-OPC circuitry, which actively limits the overshoot caused by improperly terminated backplanes, unevenly distributed cards, or empty slots during low-to-high signal transitions. This improves signal integrity, which allows adequate noise margin to be maintained at higher frequencies.

High-drive GTLP backplane interface devices feature adjustable edge-rate control (ERC). Changing the ERC input voltage between low and high adjusts the B-port output rise and fall times. This allows the designer to optimize system data-transfer rate and signal integrity to the backplane load.

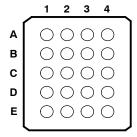
When  $V_{CC}$  is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, the output-enable  $(\overline{OE})$  input should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC – DW	Tube	SN74GTLP1395DW	GTLP1395
	SOIC - DW	Tape and reel	SN74GTLP1395DWR	GILF1395
-40°C to 85°C	TSSOP – PW	Tape and reel	SN74GTLP1395PWR	GP395
	TVSOP – DGV	Tape and reel	SN74GTLP1395DGVR	GP395
	VFBGA – GQN	Tape and reel	SN74GTLP1395GQNR	GP395

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### GQN PACKAGE (TOP VIEW)



#### **TERMINAL ASSIGNMENTS**

	1	2	3	4
Α	1T/C	1Y	1 <del>OEBY</del>	2T/C
В	GND	GND	2Y	2 <del>OEBY</del>
С	V <sub>CC</sub>	1 <del>OEAB</del>	ERC	1B
D	GND	GND	1A	2B
E	2 <del>OEAB</del>	2A	BIAS V <sub>CC</sub>	$V_{REF}$



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#### **FUNCTIONAL DESCRIPTION**

The output-enable ( $1\overline{OEAB}$ ,  $1\overline{OEBY}$ ) and polarity-control ( $1T/\overline{C}$ ) inputs control 1A, 1B, and 1Y.  $2\overline{OEAB}$ ,  $2\overline{OEBY}$ , and  $2T/\overline{C}$  control 2A, 2B, and 2Y.

 $\overline{\text{OEAB}}$  controls the activity of the B port. When  $\overline{\text{OEAB}}$  is low, the B-port output is active. When  $\overline{\text{OEAB}}$  is high, the B-port output is disabled.

A separate LVTTL A input and Y output provide a feedback path for control and diagnostics monitoring.  $\overline{OEBY}$  controls the Y output. When  $\overline{OEBY}$  is low, the Y output is active. When  $\overline{OEBY}$  is high, the Y output is disabled.

 $T/\overline{C}$  selects polarity of data transmission in both directions. When  $T/\overline{C}$  is high, data transmission is true, and A data goes to the B bus and B data goes to the Y bus. When  $T/\overline{C}$  is low, data transmission is complementary, and inverted A data goes to the B bus and inverted B data goes to the Y bus.

# FUNCTION TABLES OUTPUT CONTROL

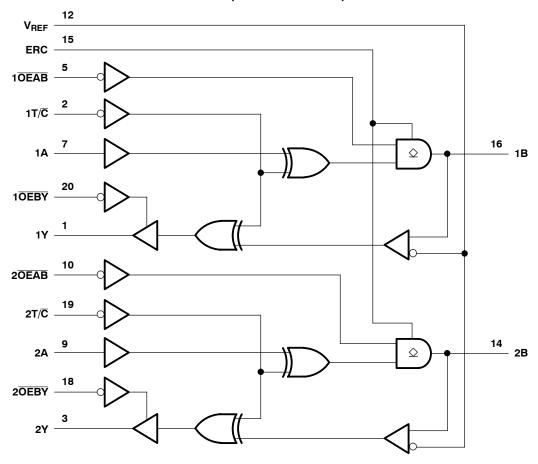
	INPUTS		OUTPUT	MODE
T/C	OEAB	OEBY	001701	MODE
Х	Н	Н	Z	Isolation
Н	L	Н	A data to B bus	True transparent
Н	Н	L	B data to Y bus	True transparent
Н	L	L	A data to B bus, B data to Y bus	True transparent with feedback path
L	L	Н	Inverted A data to B bus	Inverted transparent
L	Н	L	Inverted B data to Y bus	Inverted transparent
L	L	L	Inverted A data to B bus, Inverted B data to Y bus	Inverted transparent with feedback path

#### **OUTPUT EDGE-RATE CONTROL (ERC)**

INPUT ERC LOGIC LEVEL	OUTPUT B-PORT EDGE RATE
Н	Slow
L	Fast

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## **LOGIC DIAGRAM (POSITIVE LOGIC)**



Pin numbers shown are for the DGV, DW, and PW packages.



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# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub> BIAS V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
V	A inputs, ERC, and control inputs		-0.5	7	V
V <sub>I</sub>	Input voltage range (2)	B port and V <sub>REF</sub>	-0.5	4.6	V
V	Voltage range applied to any output	Y outputs	-0.5	7	V
Vo	in the high-impedance or power-off state (2)	B port	-0.5	4.6	V
	Company into any output in the law state	Y outputs		48	A
I <sub>O</sub>	Current into any output in the low state	B port		200	mA
Io	Current into any output in the high state (3)			48	mA
	Continuous current through each V <sub>CC</sub> or GND			±100	mA
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
		DGV package		92	
	Dealer we the surred in a red one of (1)	DW package		58	°C 141
$\theta_{JA}$	Package thermal impedance (4)	GQN package		78	°C/W
		PW package		83	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

This current flows only when the output is in the high state and  $V_{\rm O} > V_{\rm CC}$ . The package thermal impedance is calculated in accordance with JESD 51-7.

### **SN74GTLP1395**

## TWO 1-BIT LVTTL-TO-GTLP ADJUSTABLE-EDGE-RATE BUS TRANSCEIVERS WITH SPLIT LYTTL PORT, FEEDBACK PATH, AND SELECTABLE POLARITY



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## Recommended Operating Conditions (1)(2)(3)(4)

			MIN	NOM	MAX	UNIT
$V_{CC}$ BIAS $V_{CC}$	Supply voltage		3.15	3.3	3.45	V
M	Tormination valtage	GTL	1.14	1.2	1.26	V
$V_{TT}$	Termination voltage	GTLP	1.35	1.5	1.65	\ \
.,	Deference vallege	GTL	0.74	0.8	0.87	V
$V_{REF}$	Reference voltage	GTLP	0.87	1	1.1	\ \
V	lanut valtana	B port			V <sub>TT</sub>	V
V <sub>I</sub>	Input voltage  High-level input voltage	Except B port		V <sub>CC</sub>	5.5	\ \ \
.,	High-level input voltage	B port	V <sub>REF</sub> + 0.05			V
$V_{IH}$		Except B port	2			V
V	Low level input voltage	B port			V <sub>REF</sub> - 0.05	V
$V_{IL}$	Low-level input voltage	Except B port			0.8	\ \
I <sub>IK</sub>	Input clamp current	·			-18	mA
I <sub>OH</sub>	High-level output current	Y outputs			-24	mA
	Law law law day day day	Y outputs			24	A
I <sub>OL</sub>	Low-level output current	B port			100	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled			10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	,	20			μs/V
T <sub>A</sub>	Operating free-air temperature		-40		85	°C

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Proper connection sequence for use of the B-port I/O precharge feature is GND and BIAS  $V_{CC}$  = 3.3 V first, I/O second, and  $V_{CC}$  = 3.3 V last, because the BIAS  $V_{CC}$  precharge circuitry is disabled when any  $V_{CC}$  pin is connected. The control and  $V_{REF}$  inputs can be connected anytime, but normally are connected during the I/O stage. If B-port precharge is not required, any connection sequence is acceptable, but generally, GND is connected first.

 $V_{TT}$  and  $R_{TT}$  can be adjusted to accommodate backplane impedances if the dc recommended  $I_{OL}$  ratings are not exceeded.  $V_{REF}$  can be adjusted to optimize noise margins, but normally it is two-thirds  $V_{TT}$ . TI-OPC is enabled in the A-to-B direction and is activated when  $V_{TT} > 0.7 \text{ V}$  above  $V_{REF}$ . If operated in the A-to-B direction,  $V_{REF}$  should be set to within 0.6 V of  $V_{TT}$  to minimize current

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#### **Electrical Characteristics**

over recommended operating free-air temperature range for GTLP (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP <sup>(1)</sup>	MAX	UNIT	
V <sub>IK</sub>		V <sub>CC</sub> = 3.15 V,	I <sub>I</sub> = -18 mA			-1.2	V	
		V <sub>CC</sub> = 3.15 V to 3.45 V,	I <sub>OH</sub> = -100 μA	V <sub>CC</sub> - 0.2				
$V_{OH}$	Y outputs	V <sub>CC</sub> = 3.15 V	I <sub>OH</sub> = -12 mA	2.4			V	
		V <sub>CC</sub> = 3.15 V	I <sub>OH</sub> = -24 mA	2				
	Y outputs	V <sub>CC</sub> = 3.15 V to 3.45 V,	$I_{OL}$ = 100 $\mu$ A			0.2		
		V315V	I <sub>OL</sub> = 12 mA			0.4		
$V_{OL}$		VCC = 0.13 V	I <sub>OL</sub> = 24 mA			0.5	V	
<b>v</b> OL	B port  A-port and		I <sub>OL</sub> = 10 mA			0.2	<b>v</b>	
		V <sub>CC</sub> = 3.15 V	I <sub>OL</sub> = 64 mA			0.4		
		V <sub>CC</sub> = 3.45 V,	I <sub>OL</sub> = 100 mA			0.55		
<sub> </sub> (2)	A-port and control inputs	V <sub>CC</sub> = 3.45 V,	$V_{I} = 0 \text{ to } 5.5 \text{ V}$			±10	μΑ	
I <sub>OZ</sub> <sup>(2)</sup>	Y outputs	$V_{CC} = 3.45 \text{ V},$	$V_0 = 0 \text{ to } 5.5 \text{ V}$			±10	μA	
'OZ`	B port	$V_{CC}$ = 3.45 V, $V_{REF}$ within 0.6 V of $V_{TT}$ ,	$V_0 = 0 \text{ to } 2.3 \text{ V}$			±10	μ	
		$V_{CC} = 3.45 \text{ V}, I_{C} = 0,$	Outputs high			20		
$I_{CC}$	$V_{CC} = 3.15 \text{ V}$ $V_{CC} = 3.15 \text{ V}$ $V_{CC} = 3.15 \text{ V}$ $V_{CC} = 3.45 \text{ V},$	Outputs low			20	mA		
		V <sub>I</sub> (B port) = V <sub>TT</sub> or GND	Outputs disabled	V <sub>CC</sub> - 0.2  2.4  2  () () () () () () () () () () () () ()	20			
$\Delta I_{CC}^{(3)}$						1.5	mA	
<u></u>	A-port inputs	V <sub>1</sub> = 3.15 V or 0			4	4.5	nE	
Cı	Control inputs	v  = 3.13 v 01 0			3.5	5	pF	
C <sub>o</sub>	Y outputs	V <sub>O</sub> = 3.15 V or 0			5	5.5	pF	
C <sub>io</sub>	B port	V <sub>O</sub> = 1.5 V or 0			7	10.5	pF	

- All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.
- This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.

#### Hot-Insertion Specifications for A Inputs and Y Outputs

over recommended operating free-air temperature range

PARAMETER		TEST CONDITIONS				
l <sub>off</sub>	$V_{CC} = 0$ ,	$V_I$ or $V_O = 0$ to 5.5 V			10	μΑ
l <sub>ozpu</sub>	$V_{CC} = 0 \text{ to } 1.5 \text{ V},$	$V_0 = 0.5 \text{ V to 3 V},$	OEBY = 0		±30	μΑ
I <sub>OZPD</sub>	V <sub>CC</sub> = 1.5 V to 0,	V <sub>O</sub> = 0.5 V to 3 V,	OEBY = 0		±30	μΑ

### **Live-Insertion Specifications for B Port**

over recommended operating free-air temperature range

PARAMETER		TEST CONDITIONS				MAX	UNIT
I <sub>off</sub>	V <sub>CC</sub> = 0,	BIAS $V_{CC} = 0$ ,	$V_I$ or $V_O = 0$ to 1.5 V			10	μΑ
I <sub>OZPU</sub>	$V_{CC} = 0 \text{ to } 1.5 \text{ V},$	BIAS $V_{CC} = 0$ ,	$V_0 = 0.5 \text{ V to } 1.5 \text{ V},$	$\overline{OEAB} = 0$		±30	μΑ
I <sub>OZPD</sub>	V <sub>CC</sub> = 1.5 V to 0,	BIAS $V_{CC} = 0$ ,	$V_0 = 0.5 \text{ V to } 1.5 \text{ V},$	$\overline{OEAB} = 0$		±30	μΑ
I <sub>CC</sub>	V <sub>CC</sub> = 0 to 3.15 V	DIACV 0.45 V to 0.45 V	V (D 1) 01-45V			5	mA
(BIAS V <sub>CC</sub> )	V <sub>CC</sub> = 3.15 V to 3.45 V	BIAS $V_{CC} = 3.15 \text{ V to } 3.45 \text{ V},$	$V_O$ (B port) = 0 to 1.5 V			10	μΑ
V <sub>O</sub>	V <sub>CC</sub> = 0,	BIAS $V_{CC} = 3.3 \text{ V}$ ,	I <sub>O</sub> = 0		0.95	1.05	V
Io	V <sub>CC</sub> = 0,	BIAS V <sub>CC</sub> = 3.15 V to 3.45 V,	V <sub>O</sub> (B port) = 0.6 V		-1		μΑ

### **SN74GTLP1395**

## TWO 1-BIT LVTTL-TO-GTLP ADJUSTABLE-EDGE-RATE BUS TRANSCEIVERS WITH SPLIT LVTTL PORT, FEEDBACK PATH, AND SELECTABLE POLARITY



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## **Switching Characteristics**

over recommended ranges of supply voltage and operating free-air temperature,  $V_{TT}$  = 1.5 V and  $V_{REF}$  = 1 V for GTLP (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE <sup>(1)</sup>	MIN	TYP <sup>(2)</sup> MA	X UNIT	
t <sub>PLH</sub>	Α	В	Slow	3.3	6	3	
t <sub>PHL</sub>	A	Б	Slow	1.9		ns 6	
t <sub>PLH</sub>	A	В	Fast	2.5	5		
t <sub>PHL</sub>	A	Ь	Fasi	1.6	4	9 ns	
t <sub>PLH</sub>	Α Α	Y	Slow	3.4	9	7	
t <sub>PHL</sub>	A	T	Slow	3.3	9	ns 2	
t <sub>PLH</sub>	A	Υ	Fast	2.9	8	7	
t <sub>PHL</sub>	A	T	Fasi	2.9	8	ns 1	
t <sub>PLH</sub>	T/C	В	Claur	3.7	6		
t <sub>PHL</sub>	- 1/0	Б	Slow	1.8	6	ns ns	
t <sub>PLH</sub>	t <sub>PLH</sub>	ם	T/C B	Fast	1.5	5	6
t <sub>PHL</sub>	1/0	Ь	Fasi	1.7	5	ns 5	
t <sub>en</sub>	- OEAB	В	Slow	3.8	6	4	
t <sub>dis</sub>	OEAB	Ь	Slow	1.9	6	ns 1	
t <sub>en</sub>	- OEAB	В	Fast	2.8	5	3	
t <sub>dis</sub>	OLAB	D D	i asi	1.5		ns 5	
	Dina tima. P. auta	uts (20% to 80%)	Slow		2.4	200	
t <sub>r</sub>	nise time, b outp	uis (20% to 80%)	Fast		1.3	ns	
	Fall time, B outpo	uto (909/ to 209/)	Slow	3		200	
t <sub>f</sub>	raii time, b outpo	uis (60% to 20%)	Fast		2.7	ns	
t <sub>PLH</sub>	- В	Y		1.3	5		
t <sub>PHL</sub>	D	<b>T</b>		1.4	4	ns 5	
t <sub>PLH</sub>	T/C	Y		1	4	5	
t <sub>PHL</sub>	1/0	1.1	Ť		ns 4		
t <sub>en</sub>	- OEBY	Y		1	4	5	
t <sub>dis</sub>	UEDI	T		1	4	7 ns	

<sup>(1)</sup> Slow (ERC = H) and Fast (ERC = L) (2) All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.



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## Skew Characteristics<sup>(1)</sup>

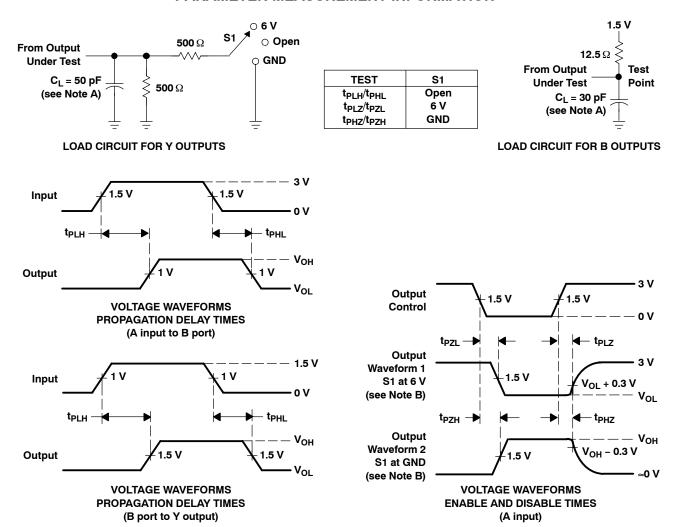
over recommended ranges of supply voltage and operating free-air temperature,  $V_{REF}$  = 1 V, standard lumped loads ( $C_L$  = 30 pF for B port and  $C_L$  = 50 pF for Y port) (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE <sup>(2)</sup>	MIN MAX	UNIT	
t <sub>sk(LH)</sub> (3)	A	В	Slow	0.3	20	
t <sub>sk(HL)</sub> (3)	A	Б	Slow	0.4	ns	
t <sub>sk(LH)</sub> (3)	$t_{sk(LH)}^{(3)}$ A B	Fast	0.3	ns		
t <sub>sk(HL)</sub> (3)	A	D Fasi	0.3	115		
t <sub>sk(LH)</sub> (3)	В	Y		0.4	20	
t <sub>sk(HL)</sub> (3)	В	'		Slow	0.2	ns
	Δ.	В	Slow	1.8		
t <sub>sk(t)</sub> (3)	Α		Fast	1.5	ns	
	В	Y		1		
t <sub>sk(prLH)</sub> (4)	^	В	Claur	0.7		
t <sub>sk(prHL)</sub> (4)	Α	D	Slow	2	ns	
t <sub>sk(prLH)</sub> (4)	Δ.	В	Fast	0.5		
t <sub>sk(prHL)</sub> (4)	A	D	rasi	1.7	ns	
t <sub>sk(prLH)</sub> (4)	В	Y		1.2		
t <sub>sk(prHL)</sub> (4)	В	Y		1.6	ns	

- (1) Actual skew values between GTLP outputs could vary on the backplane due to the loading and impedance seen by the device.
- (2) Slow (ERC = L) and Fast (ERC = H)
- (3)  $t_{sk(LH)}/t_{sk(HL)}$  and  $t_{sk(t)}$  Output-to-output skew is defined as the absolute value of the difference between the actual propagation delay for all outputs with the same packaged device. The specifications are given for specific worst-case  $V_{CC}$  and temperature and apply to any outputs switching in the same direction either high to low  $[t_{sk(HL)}]$  or low to high  $[t_{sk(LH)}]$  or in opposite directions, both low to high and high to low  $[t_{sk(t)}]$ .
- (4) t<sub>sk(prLH)</sub>/t<sub>sk(prH-L)</sub> The magnitude of the difference in propagation delay times between corresponding terminals of two logic devices when both logic devices operate with the same supply voltages and at the same temperature, and have identical package types, identical specified loads, and identical logic functions. Furthermore, these values are provided by SPICE simulations.



#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≈ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> ≈ 2 ns, t<sub>f</sub> ≈ 2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

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#### DISTRIBUTED-LOAD BACKPLANE SWITCHING CHARACTERISTICS

The preceding switching characteristics table shows the switching characteristics of the device into a lumped load (Figure 1). However, the designer's backplane application probably is a distributed load. The physical representation is shown in Figure 2. This backplane, or distributed load, can be approximated closely to a resistor inductance capacitance (RLC) circuit, as shown in Figure 3. This device has been designed for optimum performance in this RLC circuit. The following switching characteristics table shows the switching characteristics of the device into the RLC load, to help the designer better understand the performance of the GTLP device in the backplane. See www.ti.com/sc/gtlp for more information.

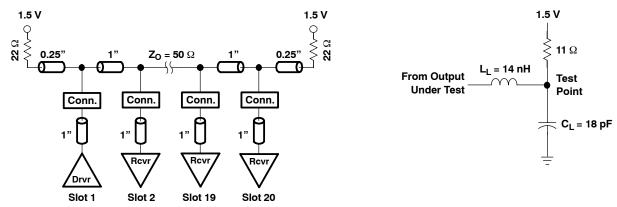


Figure 2. High-Drive Test Backplane

Figure 3. High-Drive RLC Network

## **Switching Characteristics**

over recommended operating conditions for the bus transceiver function (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE(1)	TYP <sup>(2)</sup>	UNIT
t <sub>PLH</sub>	A	В	Slow	4.3	20
t <sub>PHL</sub>	A	Ь	Slow	4.2	ns
t <sub>PLH</sub>	А	2	Fast	3.8	20
t <sub>PHL</sub>	A	В	Fasi	3.4	ns
t <sub>PLH</sub>	^	Y	Clave	6.1	
t <sub>PHL</sub>	A	Y	Slow	5.9	ns
t <sub>PLH</sub>	A	Υ	Fast	5.6	20
t <sub>PHL</sub>	A	T	Fasi	5.4	ns
	Diag time P out	nuto (200/ to 200/)	Slow	1.5	20
t <sub>r</sub>	Rise time, B out	Fast	1	ns	
	Fall time Douts	outo (000/ to 000/)	Slow	2.6	
t <sub>f</sub>	rall time, B outp	Fall time, B outputs (80% to 20%)		2	ns

- (1) Slow (ERC = H) and Fast (ERC = L)
- (2) All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . All values are derived from TI SPICE models.

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#### APPLICATION INFORMATION

#### **Operational Description**

The GTLP1395 is designed specifically for use with the TI 1394 backplane-layer controller family to transmit the 1394 backplane serial bus across parallel backplanes. But, it is a versatile two 1-bit device that also can provide multiple 1-bit clocks or an ATM read and write clock in multislot parallel backplane applications.

The 1394-1995 is an IEEE designation for a high-performance serial bus. This serial bus defines both a backplane (e.g., GTLP, VME, FB+, CPCI, etc.) physical layer and a point-to-point cable-connected virtual bus. The backplane version operates at 25, 50, or 100 Mbps, whereas the cable version supports data rates of 100, 200, and 400 Mbps. Both versions are compatible at the link layer and above. The interface standard defines the transmission method, media in the cable version, and protocol. The primary application of the cable version is the interconnection of digital A/V equipment and integration of I/O connectivity at the back panel of personal computers using a low-cost, scalable, high-speed serial interface. The primary application of the backplane version is to provide a robust control interface to each daughter card. The 1394 standard also provides new services such as real-time I/O and live connect/disconnect capability for external devices.

#### **Electrical**

The 1394 standard is a transaction-based packet technology for cable- or backplane-based environments. Both chassis and peripheral devices can use this technology. The 1394 serial bus is organized as if it were memory space interconnected between devices, or as if devices resided in slots on the main backplane. Device addressing is 64 bits wide, partitioned as 10 bits for bus ID, 6 bits for node ID, and 48 bits for memory addresses. The result is the capability to address up to 1023 buses, each having up to 63 nodes and each with 281 terabytes of memory. Memory-based addressing, rather than channel addressing, views resources as registers or memory that can be accessed with processor-to-memory transactions. Each bus entity is termed a unit, to be individually addressed, reset, and identified. Multiple nodes can reside physically in a single module, and multiple ports can reside in a single node.

Some key features of the 1394 topology are multimaster capabilities, live connect/disconnect (hot plugging) capability, genderless cabling connectors on interconnect cabling, and dynamic node address allocation as nodes are added to the bus. A maximum of 63 nodes can be connected to one network.

The cable-based physical interface uses dc-level line states for signaling during initialization and arbitration. Both environments use dominant mode addresses for arbitration. The backplane environment does not have the initialization requirements of the cable environment because it is a physical bus and does not contain repeaters. Due to the differences, a backplane-to-cable bridge is required to connect these two environments.

The signals transmitted on both the cable and backplane environments are NRZ with data-strobe (DS) encoding. DS encoding allows only one of the two signal lines to change each data bit period, essentially doubling the jitter tolerance with very little additional circuitry overhead in the hardware.

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#### **APPLICATION INFORMATION**

#### **Protocol**

Both asynchronous and isochronous data transfers are supported. The asynchronous format transfers data and transaction layer information to an explicit address. The isochronous format broadcasts data based on channel numbers rather than specific addressing. Isochronous packets are issued on the average of each 125 µs in support of time-sensitive applications. Providing both asynchronous and isochronous formats on the same interface allows both non-real-time and real-time critical applications on the same bus. The cable environment's tree topology is resolved during a sequence of events, triggered each time a new node is added or removed from the network. This sequence starts with a bus reset phase, where previous information about a topology is cleared. The tree ID sequence determines the actual tree structure, and a root node is dynamically assigned, or it is possible to force a particular node to become the root. After the tree is formed, a self-ID phase allows each node on the network to identify itself to all other nodes. During the self-ID process, each node is assigned an address. After all the information has been gathered on each node, the bus goes into an idle state, waiting for the beginning of the standard arbitration process.

The backplane physical layer shares some commonality with the cable physical layer. Common functions include: bus-state determination, bus-access protocols, encoding and decoding functions, and synchronization of received data to a local clock.

#### **Backplane Features**

- 25-, 50-, and 100-Mbps data rates for backplane environments
- Live connection/disconnection possible without data loss or interruption
- Configuration ROM and status registers supporting plug and play
- Multidrop or point-to-point topologies supported
- · Specified bandwidth assignments for real-time applications

## Applicability and Typical Application for IEEE 1394 Backplane

The 1394 backplane serial bus (BPSB) plays a supportive role in backplane systems, specifically GTLP, FutureBus+, VME64, and proprietary backplane bus systems. This supportive role can be grouped into three categories:

- Diagnostics
  - Alternate control path to the parallel backplane bus
  - Test, maintenance, and troubleshooting
  - Software debug and support interface
- System enhancement
  - Fault tolerance
  - Live insertion
  - CSR access
  - Auxiliary 2-bit bus with a 64-bit address space to the parallel backplane bus
- Peripheral monitoring
  - Monitoring of peripherals (disk drives, fans, power supplies, etc.) in conjunction with another externally wired monitor bus, such as defined by the Intelligent Platform Management Interface (IPMI)

The 1394 backplane physical layer (PHY) and the SN74GTLP1395 provide a cost-effective way to add high-speed 1394 connections to every daughter card in almost any backplane. More information on the backplane PHY devices and how to implement the 1394 standard in backplane and cable applications can be found at www.ti.com/sc/1394.

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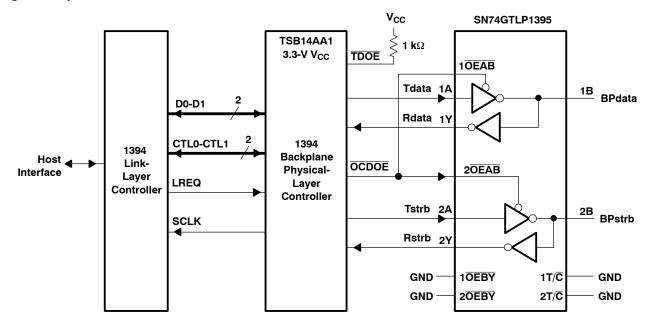


#### **APPLICATION INFORMATION**

#### SN74GTLP1395 Interface With the TSB14AA1 1394 Backplane PHY

- 1A, 1B, and 1Y are used for the PHY data signals.
- 2A, 2B, and 2Y are used for the PHY strobe signals.
- PHY N OEB D or OCDOE connects to 1 OEAB and 2 OEAB, which control the PHY transmit signals.
- 1OEBY and 2OEBY are connected to GND because the transceiver must always be able to receive signals from the backplane and relay them to the PHY.
- 1T/\overline{
- V<sub>CC</sub> is nominal 3.3 V.
- BIAS V<sub>CC</sub> is connected to nominal 3.3 V to support live insertion.
- V<sub>REF</sub> is normally 2/3 of V<sub>TT</sub>.
- ERC is normally connected to  $V_{CC}$  for slow edge-rate operation because frequencies of only 50 MHz (S100) and 25 MHz (S50) are required.

## **Logical Representation**

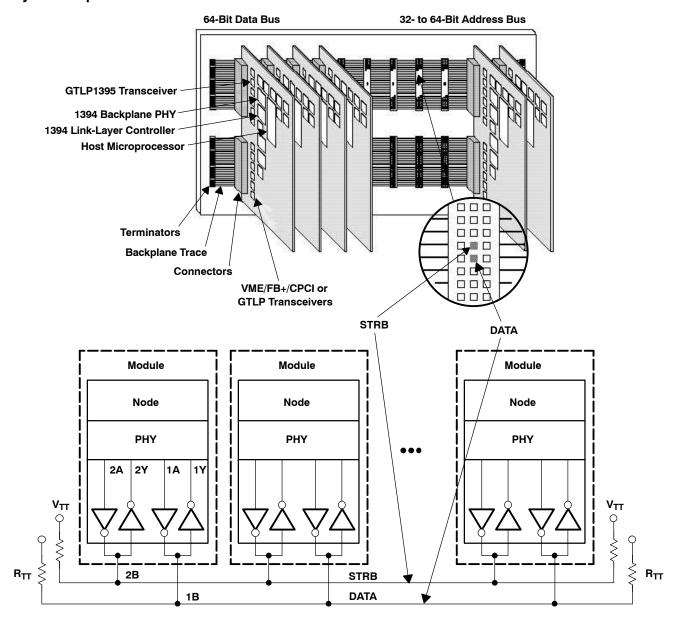


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### APPLICATION INFORMATION

## **Physical Representation**





## **PACKAGE OPTION ADDENDUM**

10-Dec-2020

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74GTLP1395DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLP1395	Samples
SN74GTLP1395PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GP395	Samples
SN74GTLP1395PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GP395	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## **PACKAGE OPTION ADDENDUM**

10-Dec-2020

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Jun-2022

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74GTLP1395DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74GTLP1395PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

www.ti.com 3-Jun-2022



## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
SN74GTLP1395DWR	SOIC	DW	20	2000	367.0	367.0	45.0	
SN74GTLP1395PWR	TSSOP	PW	20	2000	356.0	356.0	35.0	

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



#### \*All dimensions are nominal

	Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)	
ı	SN74GTLP1395PW	PW	TSSOP	20	70	530	10.2	3600	3.5	



SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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